	Hits	Search Text	DBs
1	8	(("6720217") or ("6274418") or ("6472752") or ("6642110") or ("6759299") or ("20020197777") or ("20040014269") or ("6159795") or ("2003003660")).PN.	US-PGPUB; USPAT
2	3	(("5696019") or ("6153494") or ("6436765")).PN.	US-PGPUB; USPAT
3		trench) and (periph\$5 near5	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
4	3	(flash near5 memory) and cell and periph\$5 and gate and source and drain and contact and (cell near5 trench) and ((cell near7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
5		near9 trench\$3) and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
6	3	((cell\$2 near) (region or area or transistor or	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
7	9	(flash near5 memory) and cell and periph\$5 and gate and source and drain and contact and (cell\$2 near9 trench\$3) and (periph\$5 near9 trench\$3) and ((cell\$2 near7 (region or area or transistor or memory)) same (dop\$4 or (ion near5 implant\$5) or implant\$4)) and (cell same (pad near6 oxide) same (pad near6 nitride) same perip\$7) and ((photoresist or resist) same pattern\$4 same etch\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
8	3		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
9	9	area or transistor or	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
10	9		US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
11	13	(flash near5 memory) and (cell or memory or array) and periph\$5 and gate and source and drain and ((cell\$2 or memory or array or Rmemo) near9 (STI or trench\$3)) and (periph\$5 near9 (STI or trench\$3)) and ((memory or array or cell\$2) near7 (region or area or transistor or memory)) same (dop\$4 or (ion near5 implant\$5) or implant\$4)) and ((cell or memory or array or Rmemo) same (pad near6 oxide) same (pad near6 nitride) same perip\$7) and ((photoresist or resist) same pattern\$4 same etch\$4)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
12	123	near9 (trench\$3 or STI)))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
13	140	<pre>(((cell or memory or array or Rmemo) near9 (trench\$3 or STI)) same (shallow\$3 or large\$3 or narrow\$3 or deep\$4) same ((Rperiph\$6 or periph\$5) near9 (trench\$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same (dop\$4 or (ion near5 implant\$5) or implant\$4))</pre>	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
14	94	(((cell or memory or array or Rmemo) near9 (trench\$3 or STI)) same (shallow\$3 or large\$3 or narrow\$3 or deep\$4) same ((Rperiph\$6 or periph\$5) near9 (trench\$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) near9 (dop\$4 or (ion near5 implant\$5) or implant\$4))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
15	34	(((cell or memory or array or Rmemo) near9 (trench\$3 or STI)) same (shallower or larger or narrower or deeper) same ((Rperiph\$6 or periph\$5) near9 (trench\$3 or STI))) and gate and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
16	147	(((cell or memory or array or Rmemo) near9 (trench\$3 or STI)) same (shallower or larger or narrower or deeper or steeper) same ((Rperiph\$6 or periph\$5) near9 (trench\$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same (dop\$4 or (ion near5 implant\$5) or implant\$4) same substrate same surface)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
17	4	(((cell or memory or array or Rmemo) near9 (trench\$3 or STI)) same (shallower or larger or narrower or deeper or steeper) same ((Rperiph\$6 or periph\$5) near9 (trench\$3 or STI))) and gate and source and drain and ((memory or array or cell or Rmemo) same ((dop\$4 or (ion near5 implant\$5) or implant\$4) near9 substrate near9 surface))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
18	1	F	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
19	1	430/313.ccls. and (cell or memory or array) and periph\$5 and gate and source and drain and contact and ((cell\$2 or memory or array or Rmemo) near9 (STI or trench\$3)) and (periph\$5 near9 (STI or trench\$3)) and ((memory or array or cell\$2) near7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
20			US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB
21	1	"430"/\$.ccls. and (cell or memory or array) and periph\$5 and gate and source and drain and contact and ((cell\$2 or memory or array or Rmemo) near9 (STI or trench\$3)) and (periph\$5 near9 (STI or trench\$3)) and ((memory or array or cell\$2) near7	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB

	Hits	Search Text	DBs
22	148	or STI))) and gate and	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB